



## DESCRIPTION

The A7463 series is a monolithic control circuit containing the primary functions required for DC-DC converters.

These devices consist of an internal temperature-compensated reference, comparator, controlled duty cycle oscillator with an active current limit circuit, driver and high current output switch. This series was specifically designed to be incorporated in step-down and step-up and voltage-inverting applications with a minimum number of external components.

The A7463 is available in SOP8 and DIP8 packages.

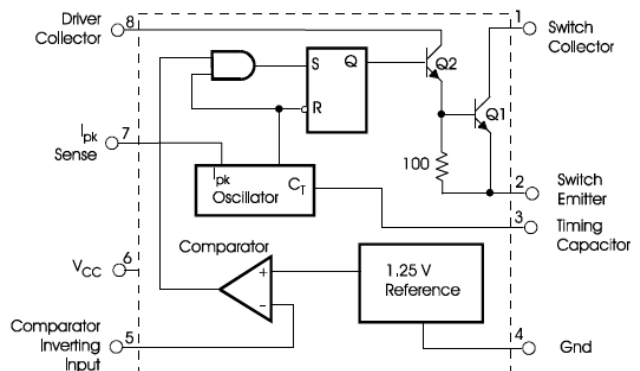
## ORDERING INFORMATION

Package Type	Part Number	
SOP8	M8	A7463M8R
		A7463M8VR
DIP8	P8	A7463P8U
		A7463P8VU
Note	V: Halogen free Package R: Tape & Reel U: Tube	
AiT provides all RoHS products Suffix “ V ” means Halogen free Package		

## FEATURES

- Operation from 3.0V to 40V input
- Low standby current
- Current limiting
- Output switch current up to 1.5 A
- Adjustable output voltage
- Operation at frequencies up to 100kHz
- Precision Reference (2%)
- Available in SOP8 and DIP8 Packages

## TYPICAL APPLICATION





## PIN DESCRIPTION

<p><b>A7463</b> <b>SOP8</b></p> <p>Top View</p>		<p><b>A7463</b> <b>DIP8</b></p> <p>Top View</p>	
Pin #	Symbol	Function	
1	SWC	Switch Collector	
2	SWE	Switch Emitter	
3	TC	Timing Capacitor	
4	GND	GND	
5	CII	Comparator Inverting Input	
6	Vcc	Vcc	
7	IPK	IPK Sense	
8	DRC	Driver Collector	



## ABSOLUTE MAXIMUM RATINGS

V <sub>CC</sub> , Power Supply Voltage	40V <sub>DC</sub>
V <sub>IR</sub> , Comparator Input Voltage Range	-0.3 to +40V <sub>DC</sub>
V <sub>C(Switch)</sub> , Switch Collector Voltage	40V <sub>DC</sub>
V <sub>E(Switch)</sub> , Switch Emitter Voltage (V <sub>Pin1</sub> =40V)	40V <sub>DC</sub>
V <sub>CE(Switch)</sub> , Switch Collector-to-Emitter Voltage	40V <sub>DC</sub>
V <sub>C(Driver)</sub> , Driver Collector Voltage	40V <sub>DC</sub>
I <sub>C(Driver)</sub> , Driver Collector Current <sup>NOTE1</sup>	100mA
I <sub>SW</sub> , Switch Current	1.5A
T <sub>J</sub> , Operating Junction Temperature	+150°C
T <sub>A</sub> , Operating Ambient Temperature Range	-40°C ~ +85°C
T <sub>STG</sub> , Storage Temperature Range	-65°C ~ + 150°C
ESD	2500V

Stress beyond above listed "Absolute Maximum Ratings" may lead permanent damage to the device. These are stress ratings only and operations of the device at these or any other conditions beyond those indicated in the operational sections of the specifications are not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

NOTE1: Maximum package power dissipation limits must be observed.



## ELECTRICAL CHARACTERISTICS

$V_{CC}=5.0V$ ,  $T_A=T_{Low}$  to  $T_{High}$ , unless otherwise specified

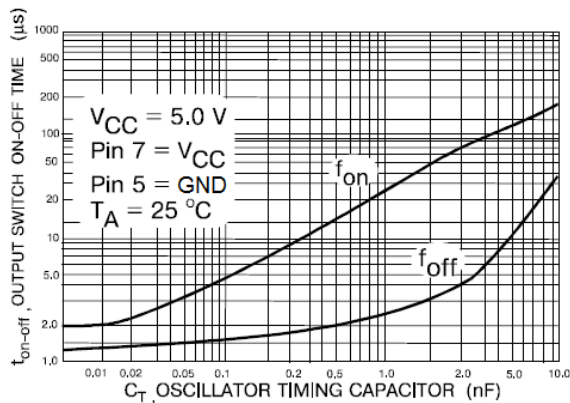
Parameter	Symbol	Conditions	Min.	Typ.	Max.	Unit
<b>OSCILLATOR</b>						
Frequency	$f_{osc}$	$V_{Pin5}=0V$ , $C_T=1.0nF$ , $T_A=25^\circ C$	24	33	42	KHz
Charge current	$I_{chg}$	$V_{CC}=5.0V$ to $40V$ , $T_A=25^\circ C$	24	35	42	$\mu A$
Discharge current	$I_{dischg}$	$V_{CC}=5.0V$ to $40V$ , $T_A=25^\circ C$	140	220	260	$\mu A$
Discharge-to-charge current ratio	$I_{dischg}/I_{chg}$	Pin7 to $V_{CC}$ , $T_A=25^\circ C$	5.2	6.5	7.5	
Current limit sense voltage	$V_{lpk(sense)}$	$I_{chg}=I_{dischg}$ , $T_A=25^\circ C$	250	300	350	mV
<b>OUTPUT SWITCH NOTE 2</b>						
Saturation voltage, Darlington connection	$V_{CE(sat)}$	$I_{Sw}=1.0A$ , Pins1, 8 connected		1.0	1.3	V
Saturation voltage, Darlington connection	$V_{CE(sat)}$	$I_{Sw}=1.0A$ , $R_{Pin8}=82\Omega$ to $V_{CC}$ , Forced $\beta =20$		0.45	0.7	V
DC current gain	$h_{FE}$	$I_{Sw}=1.0A$ , $V_{CE}=5.0$ , $T_A=25^\circ C$	50	75		
Collector off-state current	$I_{C(off)}$	$V_{CE}=40V$		40	100	$\mu A$
<b>COMPARATOR</b>						
Threshold voltage	$V_{th}$		1.225 1.21	1.25 -	1.275 1.29	V
Threshold voltage line regulation	$Reg_{line}$			1.4	5.0	mV
Input bias current	$I_{IB}$			-20	-400	nA
<b>TOTAL DEVICE</b>						
Supply current	$I_{CC}$	$V_{CC}=5.0V$ to $40V$ , $C_T=1.0nF$ , Pin7= $V_{CC}$ , $V_{Pin5}>V_{th}$ , Pin2 =GND, remaining pins - open			4.0	mA

NOTE2: Low duty cycle pulse techniques are used during the test to maintain junction temperature as close to ambient temperature as possible.

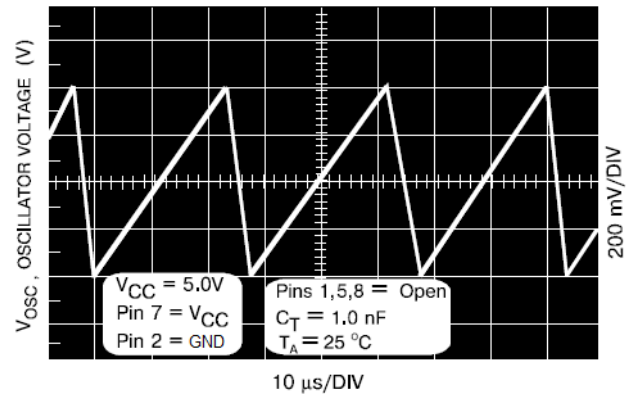


## TYPICAL PERFORMANCE CHARACTERISTICS

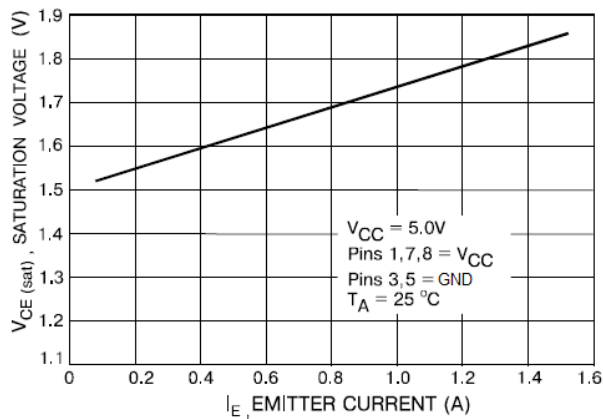
1. Output Switch on-off time versus  
Oscillator timing capacitor



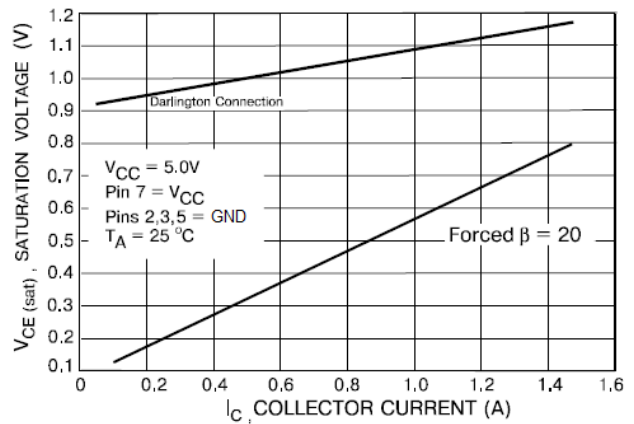
2. Timing capacitor waveform



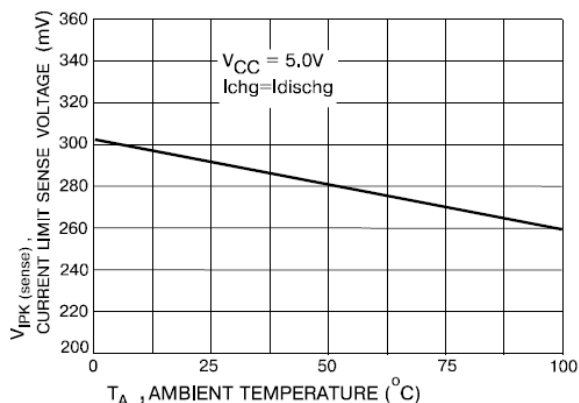
3. Emitter follower configuration output  
saturation voltage versus Emitter current



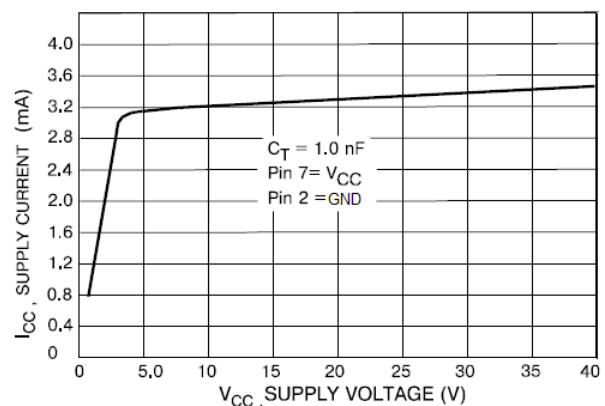
4. Common emitter configuration output  
saturation voltage versus Collector current



5. Current limit sense voltage versus Temperature



6. Standby supply current versus Supply voltage

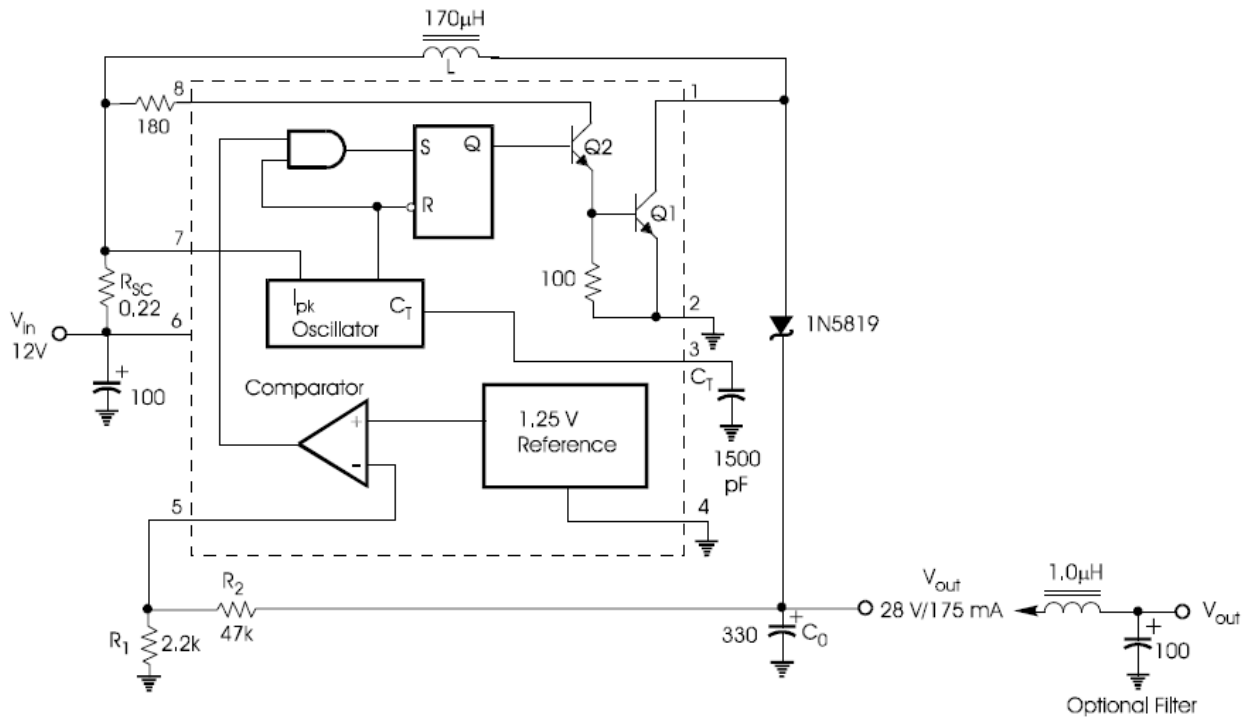




## DETAILED INFORMATION

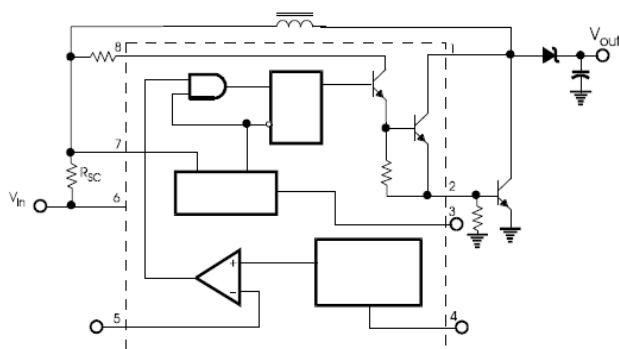
### Application Information

#### 1. Step-up converter

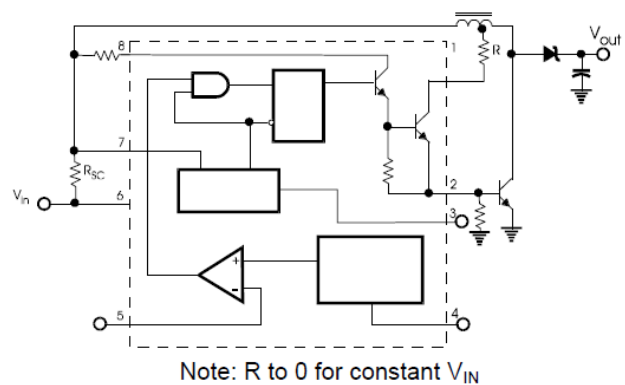


#### 2. External current boost connections for $I_{C Peak}$ greater than 1.5A

##### External NPN switch

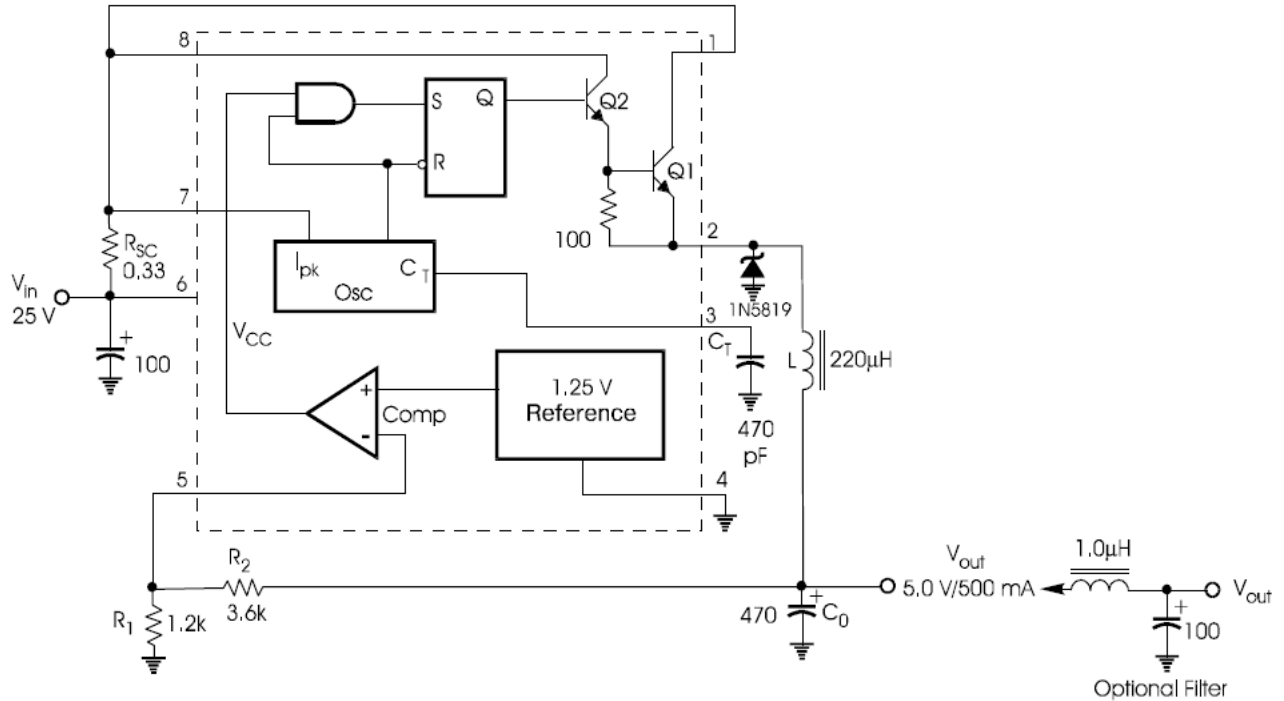


##### External NPN saturated switch



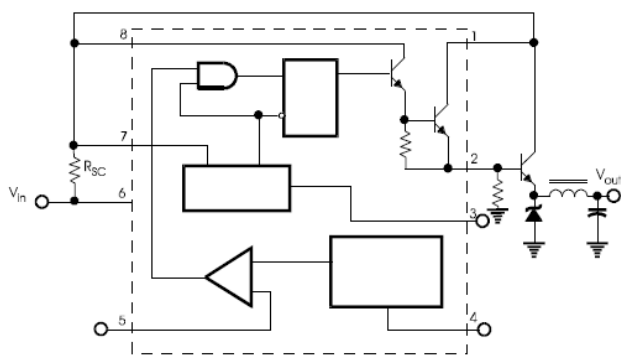


### 3. Step-down Converter

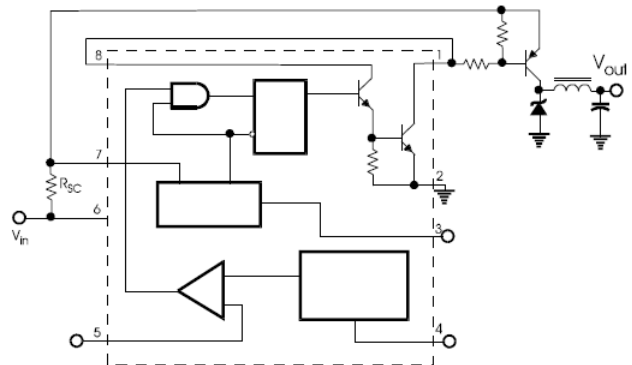


### 4. External current boost connections for $I_{C Peak}$ greater than 1.5A

External NPN switch

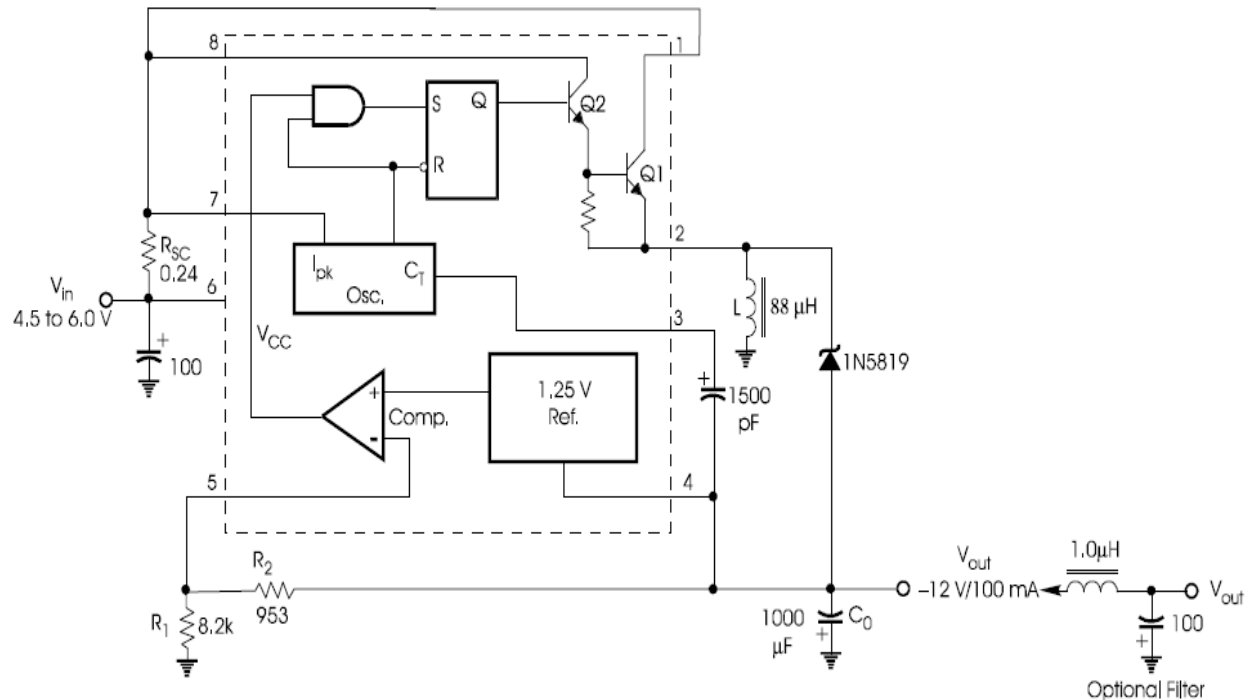


External PNP saturated switch



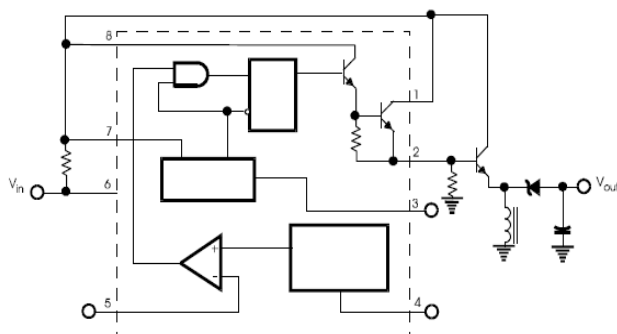


## 5. Voltage inverting converter

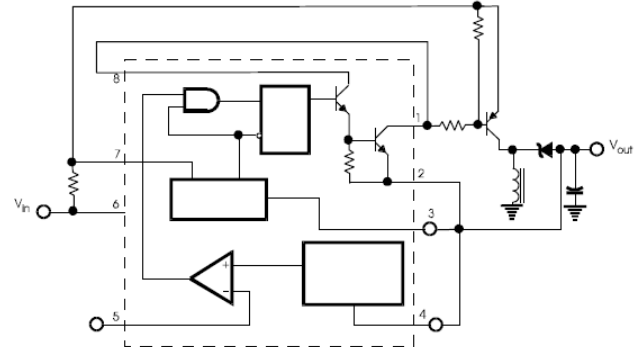


## 6. External current boost connections for $I_{C Peak}$ greater than 1.5A

### External NPN switch



### External PNP saturated switch







## Design Formula

Calculation	Step-up	Step-down	Voltage-inverting
$t_{on}$	$\frac{V_{out} + V_F - V_{in(min)}}{V_{in(min)} - V_{sat}}$	$\frac{V_{out} + V_F}{V_{in(min)} - V_{sat} - V_{out}}$	$\frac{ V_{out}  + V_F}{V_{in} + V_{sat}}$
$(t_{on} + t_{off})_{max}$	$\frac{1}{f_{min}}$	$\frac{1}{f_{min}}$	$\frac{1}{f_{min}}$
$C_T$	$4.0 \times 10^{-5} t_{on}$	$4.0 \times 10^{-5} t_{on}$	$4.0 \times 10^{-5} t_{on}$
$I_{pk(switch)}$	$2I_{out(max)} \left( \frac{t_{on}}{t_{off}} + 1 \right)$	$2I_{out(max)}$	$2I_{out(max)} \left( \frac{t_{on}}{t_{off}} + 1 \right)$
$R_{sc}$	$0.3/I_{pk(Switch)}$	$0.3/I_{pk(Switch)}$	$0.3/I_{pk(Switch)}$
$L_{(min)}$	$\left( \frac{V_{in(min)} - V_{sat}}{I_{pk(switch)}} \right) \times t_{on(max)}$	$\left( \frac{V_{in(min)} - V_{sat} - V_{out}}{I_{pk(switch)}} \right) \times t_{on(max)}$	$\left( \frac{V_{in(min)} - V_{sat}}{I_{pk(switch)}} \right) \times t_{on(max)}$
$C_o$	$9 \frac{I_{out} t_{on}}{V_{ripple(pp)}}$	$\frac{I_{pk(switch)} (t_{on} + t_{off})}{8V_{ripple(pp)}}$	$9 \frac{I_{out} t_{on}}{V_{ripple(pp)}}$

## Terms and Definitions

$V_{sat}$  – Saturation voltage of the output switch.

$V_f$  – Forward voltage drop of the output rectifier.

The following power supply characteristics must be chosen:

$V_{IN}$  – Nominal input voltage.

$V_{OUT}$  – Desired output voltage,

$$|V_{out}| = 1.25 \left( 1 + \frac{R_2}{R_1} \right)$$

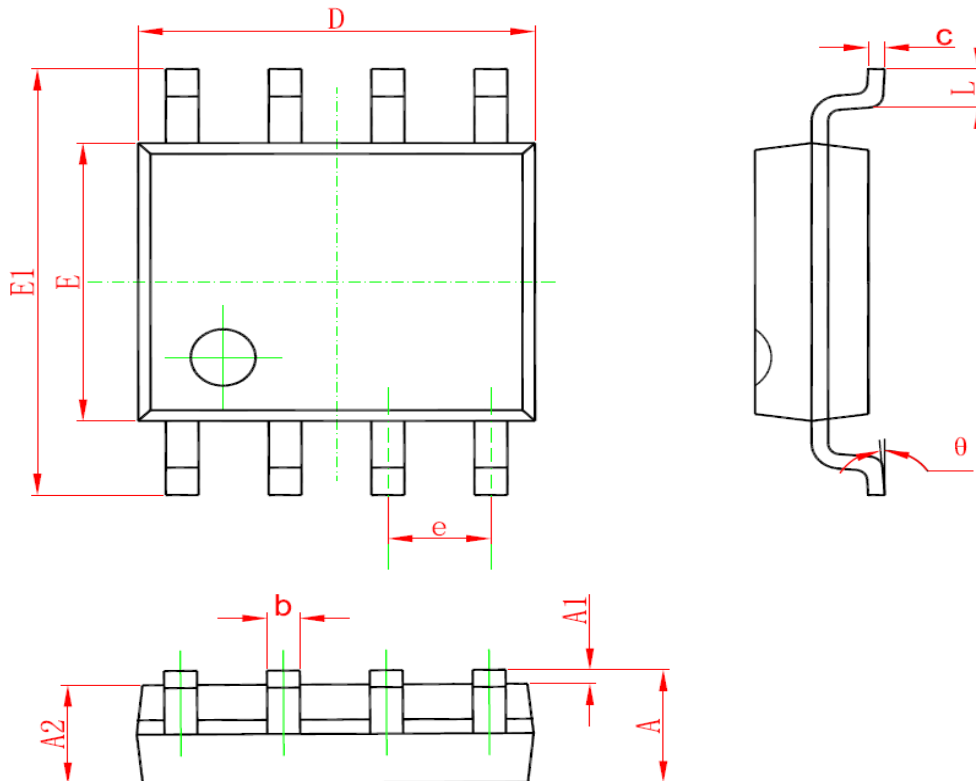
$f_{min}$  – Minimum desired output switching frequency at the selected values of  $V_{IN}$  and  $I_{OUT}$ .

$V_{ripple(p-p)}$  – Desired peak-to-peak output ripple voltage. In practice, the calculated capacitor value will need to be increased due to its equivalent series resistance and board layout. The ripple voltage should be kept to a low value since it will directly affect the line and load regulation.



## PACKAGE INFORMATION

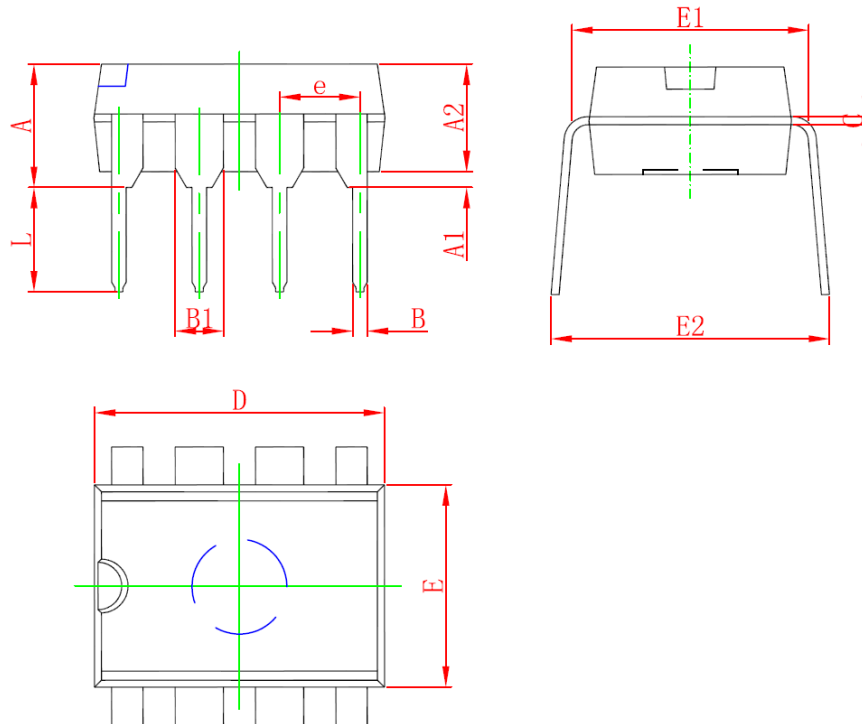
Dimension in SOP8 (Unit: mm)



Symbol	Min	Max
A	1.350	1.750
A1	0.100	0.250
A2	1.350	1.550
b	0.330	0.510
c	0.170	0.250
D	4.700	5.100
E	3.800	4.000
E1	5.800	6.200
e	1.270(BSC)	
L	0.400	1.270
$\theta$	0°	8°



Dimension in DIP8 (Unit: mm)



Symbol	Min	Max
A	3.710	4.310
A1	0.510	
A2	3.200	3.600
B	0.380	0.570
B1	1.524(BSC)	
C	0.204	0.360
D	9.000	9.400
E	6.200	6.600
E1	7.320	7.920
e	2.540(BSC)	
L	3.000	3.600
E2	8.400	9.000



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